Final Report

1994 Gordon Research Conference on Point Defects, Line Defects, and Interfaces in Semiconductors

Office of Naval Research

Grant No: N00014-94-1-0578

Principal Investigator: Michael Stavola

Scientific Officer: Larry R. Cooper



The Gordon Conference on Point Defects, Line Defects and Interfaces in Semiconductors was held from July 31 - August 5, 1994 at Plymouth State College in Plymouth, New Hampshire. The conference chair was Michael Stavola, Lehigh University, and the vice-chair was Leonard Feldman, AT&T Bell Laboratories. By any measure, the conference was highly successful.

The Final Fiscal Report for the conference will be sent by the Gordon Conference Office. A summary of the final budget is attached to this report (Sec. A). Conference funds were used primarily to support the registration fees of participants. Of those supported, roughly 28 were invited speakers or discussion leaders, 14 were graduate students or postdocs, and 14 were other professionals. The registration fees that were provided allowed many attendees to obtain travel support from their home institutions. These funds greatly increased the number of qualified scientists who could attend and also the quality of the meeting. The interest and support of the agencies listed on p. A-1 are greatly appreciated by the community working on defects in semiconductors.

There is no abstract booklet or proceedings printed for a Gordon Conference. The invited program (Sec. B) and poster program (Sec. C) are included here as the final technical report. The invited program was constructed from suggestions solicited from the defects community by a program committee that included J. Chadi, NEC, L. Feldman, AT&T, W.B. Fowler, Lehigh, R. Hull, AT&T, P. Mooney, IBM, G.D. Watkins, Lehigh, and N. Wilsey, NRL. There were 23 invited presentations and 50 posters. The invited talks were extremely well received. These were followed by long productive discussion periods that were organized by the session's discussion leader.

19950125 056

DTIC QUALITY INSPECTED 3

DESTRIBUTION STATEMENT

Approved for public releases
Distribution United

The technical program has continued to evolve and to deal with the hottest new issues in the field of defects. There were two sessions on defects in wide bandgap semiconductors like the group III nitrides and II-VI materials that are receiving much recent attention because of renewed interest in visible optical devices. The presentation of very fundamental research was mixed with device-related defect problems which led to well balanced sessions which should help the community to focus on important issues. Heteroepitaxy and related defect issues continue to play an important role. Talks on strain relief in SiGe epitaxial layers and on the interactions of defects with surfaces and interfaces were especially exciting and well received. Studies of point defects continue to generate exciting results. The talks by Johnson and Estreicher on hydrogen in semiconductors raised several controversial issues which were vigorously discussed.

The Gordon Conference evaluation of the Point and Line Defect Conference came out very well (Sec. D). The conference was rated as well above average in all areas which include Science, Discussion, Management, and Atmosphere. Rating scores were higher than the previous conference in this series in all categories. The quality of the discussion periods was rated especially highly in comments by the attendees. The profile sheet shows that there was a very healthy balance in the age distribution, location and professional status of the attendees. For example 50% of the attendees were from U.S. institutions and 50% were non-U.S.; 29% were students or postdocs and 71% were professionals. There were 114 attendees at the meeting. A list of conference attendees is attached (Sec. E).

The next Gordon Conference on Point Defects, Line Defects and Interfaces in Semiconductors will be held in summer 1996. The meeting chair will be Leonard Feldman, At&T Bell Laboratories (elected at the 1992 meeting) and the meeting vice-chair will be Chris G. Van de Walle (elected at the 1994 meeting).

| Acces | 206 | |
|-------|------------|--------|
| | ssion For | |
| NTIS | GRA&I | V |
| DITIC | | ñ |
| | iomaceq | ñ |
| Justi | Lication_ | |
| | 1. 11-11 | |
| By_ | erlelle | と |
| Diste | ibation/ | . 66 |
| Ava1 | lability C | odes . |
| | Avail and/ | OF. |
| Pist | Special | l |
| . 11 | 1 | |
| D'II | ģ | 1 |
| | j | 35. |
| 4 | - | |

DTIC QUALITY INSPECTED 3

A. CONFERENCE FINANCES

CONFERENCE SUPPORT

| Gordon Research Conference Special Fund | \$15,000 |
|---|--------------|
| Gordon Research Conference Chair's Fund | 600 |
| Gordon Research Conference Supplement | 500 |
| Office of Naval Research* | 3,000 |
| Army Research Office* | <u>5,000</u> |
| TOTAL | \$24,100 |

In addition to the above, the International Science Foundation fully supported the travel expenses of two attendees from the Former Soviet Union.

CONFERENCE EXPENSES

| Registration Fees for Invited Speakers and Discussion Leaders* | \$12,200 |
|--|----------|
| Registration Fees and Travel Support for Participants | 6,800 |
| Registration Fees for Students and Postdocs | 4,500 |
| Miscellaneous Administrative Expenses | _600 |
| TOTAL | \$24,100 |

^{*}Funds provided by the U.S. Navy Office of Naval Research and the U.S. Army Research Office were used to partially support the expenses of invited speakers and discussion leaders.

B. Conference Program

Gordon Research Conference Point Defects, Line Defects, and Interfaces in Semiconductors

Plymouth State College (South), Plymouth, NH USA July 31-August 5, 1994

Chair: Michael Stavola

Vice Chair: L.C. Feldman

Monday 8:50 am

M. Stavola (Lehigh)

Welcome

G.D. Watkins (Lehigh)

in memory of James W. Corbett

Monday 9:00 am-12:15 pm

Lattice Location of Impurities

Discussion leader: B. Clerjaud (Paris)

J.E. Northrup (Xerox)

Si Doping and Diffusion in GaAs

P.H. Citrin (AT&T)

EXAFS and NEXAFS Studies of Point Defects in

Semiconductors

R.C. Newman (London)

The Dynamics of H-CAS Pairs in GaAs and AlAs

Deduced from LVM Spectroscopy

Monday 7:30 pm

Advances in Structure Sensitive Techniques

Discussion leader: W. Jantsch (Linz)

C. Corbel (Saclay)

Positron Annihilation Studies of Charge States and

Metastability of Defects in Semiconductors

J.-M. Spaeth (Paderborn)

Electrical Detection of Electron Paramagnetic

Resonance: New Possibilities for the Study of Point

Defects

Tuesday 8:45 am-12:15 pm

Wide-Band-Gap Semiconductors I

Discussion leader: B. Monemar (Linköping)

B.K. Meyer (Munich)

ODMR of Defects in CdZnTe

E.R. Glaser (NRL)

Optical and Magnetic Resonance Studies of Point

Defects in GaN

Discussion leader: H. Kukimoto (Tokyo Inst. of Tech.)

K. Nakano (SONY)

Characterization of ZnMgSSe Blue Laser Diodes

Tuesday 7:30 pm

Wide-Band-Gap Semiconductors II

Discussion leader: C.G. Van de Walle (Xerox)

J.D. Chadi (NEC)

DX Centers in II-VI Semiconductors

P. Boguslawski (Warsaw)

Impurities and Defects in Wide Gap Nitrides

Wednesday 8:45 am-12:15 pm Hydrogen in Semiconductors

Discussion leader: J. Weber (MPI Stuttgart)

N.M. Johnson (Xerox) Diffusion and Charge States of Isolated Hydrogen in

Si and GaAs

S.K. Estreicher (Texas Tech) States and Diffusion Properties of Hydrogen in

Semiconductors: A View from Theory

Discussion leader: E.H. Poindexter (Fort Monmouth)

E.A. Cartier (IBM) Interaction of Atomic H with the Si/SiO₂ Interface

Wednesday 7:30 pm Dislocations

Discussion leader: E.R. Weber (Berkeley)

R. Jones (Exeter) Impurity-Dislocation Interaction in Si and GaAs

B. Farber (Case-Western) A New Approach for Studying Kink Dynamics on

Dislocations in Semiconductors

Thursday 8:45 am-12:15 pm Heteroepitaxy

Discussion leader: E.A. Fitzgerald (AT&T)

K.L. Kavanagh (UCSD) Strain Relaxation of InGaAs/GaAs

F.K. LeGoues (IBM) Strain Relief in SiGe on Si

Diffusion

Discussion leader: U.M. Gösele (MPI Halle)

N. Moriya (AT&T) B Diffusion in SiGe Epitaxial Layers

A. Nylandsted Larsen (Aarhus) Enhanced Diffusion of High Concentration Impurities

in Si: A Collective Phenomenon?

Thursday 7:30 pm After Banquet Presentation

Discussion leader: J.M. Langer (Warsaw)

E.E. Haller (UC Berkeley) Physics with Isotopically Controlled Semiconductors

Friday 8:30 am-11:30 am Interfaces, Defects, and Epitaxy

Discussion leader: M. Scheffler (Berlin)

B. Bennett (NRL) Interfacial Characterization and Control in

Arsenide/Antimonide Heterostructures

H.J. Osten (Frankfurt, Oder) The Role of Foreign Atoms in Epitaxy

J.D. Tersoff (IBM) Interactions of Defects with Surfaces and Interfaces

C. PROGRAM FOR POSTER SESSIONS

July 28, 1994

Gordon Conference on Point Defects, Line Defects and Interfaces - 1994

Poster Sessions

Session 1:

Session 2:

Posters on Display Monday and Tuesday "Official Viewing" Tuesday Evening Posters M1-M6, T1-T14

Posters on Display Wednesday and Thursday "Official Viewing" Wednesday Evening Posters W1-W7, Th1-Th6, F1-F17

M- Novel Techniques

M-1 First use of radioactive dopants for a photoluminescence study: GaAs doped with In decaying to III Cd

R. Magerle, A. Burchard, M. Deicher, T. Kerle, W. Pfeiffer, Konstanz

M-2 Effective Mass in Hydrogen-Impurity Pairs: The Roles of Anharmonicity and Lattice Interaction

S.N. Walck, W.B. Fowler, Lehigh

M-3 Ultrasound Stimulated Change of Diffusion Length in Si: New Approach in Defect Engineering

S. Ostapenko, South Florida

M-4 Ultrasound Enhancement of Cr-B Pairing in CZ Si

Ronald E. Ball II, U. South Florida

M-5 Characterization of defects in plastically deformed semiconductors

H.S. Leipner, R. Krause-Rehberg, A. Polity, T. Drost, O.Storbeck, Tohoku U.

M-6 Identification of Group-V Impurity-Related Complexes in Germanium Using Positron Annihilation as a Microscope Probe

V. Emtsev A.F. Ioffe, Russian Acad. Sciences

T- Wide Band Gap Materials

T-1 Deep iron acceptors in GaN and AIN

K. Maier, J. Baur, M. Kunzer, U. Kaufmann, J. Schneider, Fraumhofer-IAF

T-2 Formation Energies and Electronic Structure of Native Defects in GaN

J. Neugebauer, C.G. Van de Walle, Xerox

T-3 Non-Linear Spectroscopy of Deep Levels. Centres of Radiative and Nonradiative Recomination in ZnSe:Te

G. Raciukaitis, Vilnius U.

T-4 Nonlinear spectroscopic methods for the study of deep local defects of crystals V. Gavryushin, G. Raciukaitis, A. Kazlauskas, Vilnius U.

T-5 Symmetry and Electronic Structure of the Mn-Impurity in ZnS Nanocrystals T.A. Kennedy, P.B. Klein, E.R. Glaser, Naval Research Lab.; R.N. Bhargava, Nanocrystals Tech.

- T-6 Identification of the neutral V^{4+} impurity in cubic 3C-SiC by electron-spin resonance and optically detected magnetic resonance
- M. Kunzer, K.F. Dombrowski, U. Kaufmann, K. Maier, J. Schneider, Fraunhofer Inst.; V. Shields, M.G. Spencer, Howard U.
- T-7 Strain-stablilized highly-concentrated pseudomorphic Si_{1-x} C_x layers in Si H. Rücker, M. Methfessel, E. Bugiel, H.J. Osten, Inst. für Halbleiterphysik
- T-8 Microscopic structures of donors and acceptors in SiC
- S. Greulich-Weber, M. Feege, J.-M. Spaeth, E.N. Kalabukhova, S.N. Lukin, E.N. Mokhov
- T-9 Nickel Related Defects in High Pressure Synthetic Diamond M.H. Nazare, J.C. Lopes, L.M. Rino, U. Aveiro
- T-10 ODMR of Nitrogen and Nickel in Diamond
- P.W. Mason, G.D. Watkins, Lehigh U.; M.H. Nazare, U. de Aveiro.
- T-11 Phosphorous Doping of Diamond: an EPR Study
- M.E. Zvanut, U. Alabama; W.E. Carlos, Naval Res. Lab.; J.A. Freitas, Jr., Sachs Freeman Assoc.; K. Jamison, Si Diamond Tech.
- T-12 Room Temperature Electric Field-Induced Control Over Composition and Properties of Chalcogenide Semiconductors
- L. Chernyak, D. Cahen, I. Lyubomirsky, Weizmann Inst. Sci.
- T-13 A DX Behavior for Holes Implied from Observation of Metastable Acceptor States J. Han, M.D. Ringle, Y. Fan, R.L. Gunshor, Purdue U.; A.V. Nurmikko, Brown U.
- T-14 A New Tight-Binding Model for the Study of Materials M.J. Burnhard, G.G. DeLeo, Lehigh U.

W- Hydrogen in Semiconductors and Dislocations

- W-1 Microscopic structure of donor-two-hydrogen complexes in n-type crystalline silicon
- Z.N. Liang, C. Hass, L. Niesen, Groningen U.; P.J.H. Denteneer, Leiden U.
- W-2 Hydrogen Vibrations of Three Charge States of the Pt-H₂ Center in Si
- S. Uftring, M. Stavola, P.M. Williams, G.D. Watkins, Lehigh U.
- W-3 Preferential alignment of complexes containing carbon and hydrogen in GaAs epilayers grown by metal-organic vapour phase epitaxy (MOVPE)
- B.R. Davidson, R.C. Newman, Imperial College; K.H. Bachem, Fraunhofer Inst.
- W-4 Atomic Modes of Dislocation Mobility in Silicon
- V.V. Bulatov, S. Yip, A.S. Argon, MIT
- W-5 Plasma Etching of Dislocations in Silicon
- E.M. Nadgorny, Mich. Tech. U
- W-6 Effect of Dislocations on the Reactive Ion Etching of Silicon Surfaces
- E.M. Nadgorny, Mich. Tech. U
- W-7 Hydrogen-related shallow thermal donors in Czochralski silicon
- S.A. McQuaid, R.C. Newman, Imperial College.

Th- Heteroepitaxy and Diffusion

- TH-1 Electrical and Optical States Related to Dislocations in $Si_{1-x}Ge_x$ Layers L.P. Tilly, P.M. Mooney, F.K. LeGoues, J.O. Chu, S. Zollner, R.T. Collins, IBM
- TH-2 Photoluminescence of Si_{1-x}Ge_x Double and Triple Quantum Wells
- H.-M. Latuske, U. Mantz, K. Thonke, R. Sauer, U. Ulm; F. Schäffler, H.-J. Herzog, Daimler-Benz
- TH-3 Diffusion in Strained SiGe
- N. Cowern, Philips Res
- TH-4 Boron Diffusion in $Si_{1-x}Ge_x$
- P. Kuo, J.L. Hoyt, J.F. Gibbons, Stanford U.; J.E. Turner, D. Lefforge, T.I. Kamins, Hewlett-Packard
- TH-5 Isoconcentration Study of Phosphorus Diffusion in Silicon
- F. Wittel, S. Dunham, Boston U.
- TH-6 Si and Be Diffusion in GaAs Delta Doping Layers Studied by Magneto-Transport and Scanning Tunneling Microscopy
- P.M. Koenraad, Eindhoven; M.B.J. Johnson, H.W.M. Salemink, J.H. Wolter, IBM; J.A.A.J. Perenboom, U. Nijmegen

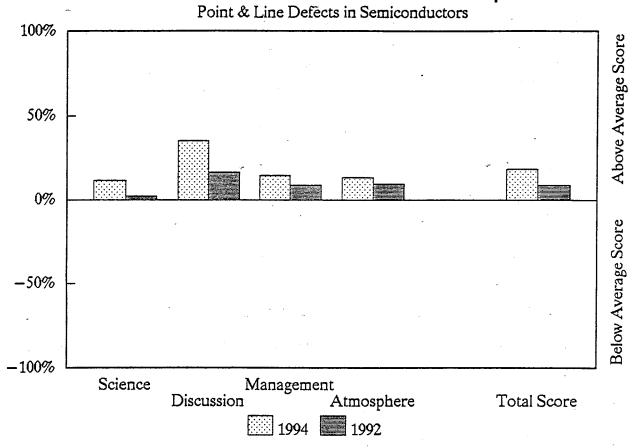
F- Defects and "Granular" Si

- F-1 Investigation of As_{Ga} Related Defects in Low Temperature Grown GaAs through MCDA and ODMR
- A. Prasad, X. Liu, W.M. Chen, E.R. Weber, U. CA Berkeley

- F-2 Defects in GaAs Grown at Low Temperature
- C.G. Morgan, J.I. Landman, Wayne State; J.T. Schick, Villanova
- F-3 Metastable Radiation Induced Defects in GaAs
- F.D. Auret, S.A. Goodman, R.M. Erasmus, W.E. Meyer, U. Pretoria
- F-4 Passivation of Shallow and Deep Levels by Lithium in GaAs
- H.P. Gislason, T. Egilsson, Baohua Yang, U. Iceland
- F-5 Local Investigation of the Electrical Properties of Grain Boundaries in Silicon
- J. Palm, MIT; D. Steinbach, H. Alexander, U. Köln
- F-6 Light Emission Properties of Porous Silicon
- S.M. Prokes, Naval Res
- F-7 Metastability of Electronic Defects Caused by Configuration and Temperature Dependent Entropy Variation
- S.V. Koveshnikov, A. Agarwal, G.A. Rozgonyi, N.C. State
- F-8 Recent Applications of Spin-Dependent Recombination in Group IV Semiconductors
- M.S. Brandt, C.F.O. Graeff, M. Stutzmann, Walter Schottky Inst
- F-9 The Nitrogen-Pair Defect in Silicon, Germanium and Silicon-Germanium Alloys
- F.B. Rasmussen, B.B. Nielsen, U. Aarhus; R. Jones, U. Exeter, S. Oberg, U. Lulea
- F-10 Structure of the Neutral Charge State of Interstitial Carbons in Si
- J.F. Zheng, M. Stavola, G.D. Watkins, Lehigh U.
- F-11 Lattice Relaxations and Bound Excitons
- G. Davies, King's College
- F-12 The Electrical Properties of He-Implantation-Produced Nanocavities in Silicon
- C.H. Seager, S.M. Myers, R.A. Anderson, W.L. Warren, D.M. Follstaedt, Sandia
- F-13 EPR of Au-Complexes in Heat-Treated Silicon
- P.M. Williams, G.D. Watkins, Lehigh U.
- F-14 Alternative Defect Model for Si-NL52
- K.L. Brower, S.M. Myers, Sandia; A.H. Edwards, U. North Carolina; N.M. Johnson, Chris G. Van de Walle, Xerox Palo Alto; E.H. Poindexter, Ft. Monmouth
- F-15 Chemical bond and reconstruction of impurity centers in semiconductors
- A. Ryskin, Vavilov State Optical Institute
- F-16 Intentional introduction of Al-O complexes into GaAs grown by Organometallic Vapor Phase Epitaxy
- Y. Park, M. Skowronski, Carnegie-Mellon U.
- F-17 Bistability of Dangling Bonds in Amorphous and Crystalline Silicon by *ab initio* Molecular Dynamics Simulation
- H. Katayama-Yoshida, Tohoku U.

D. GORDON CONFERENCE EVALUATION

1994 Overall Conference Comparison



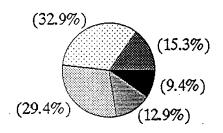
CONFERENCE SCORES:

Point & Line Defects in Semiconductors

| Conference Scores: | 1994 | 1992 | Average Conference Scores |
|--------------------|--|-------|---------------------------|
| Science: | 24.50 | 22.44 | 21.93 |
| Discussion: | 23.14 | 19.91 | 17.08 |
| Management: | 16.70 | 15.87 | 14.56 |
| Atmosphere: | 17.72 | 17.08 | 15.61 |
| | 44 44 44 44 44 44 44 44 44 44 44 44 44 | | |
| Total Score: | 82.06 | 75.30 | 69.19 |

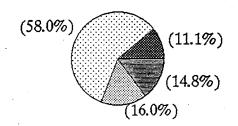
Point & Line Defects in Semiconductors Conferee Profile Sheet

Age Distribution Average Age: 41.8



20's **30**'s **40**'s **50**'s **60**+

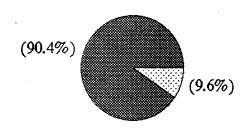
Employer/Occupation Location



■Acad. (BS/MS) **■**Government

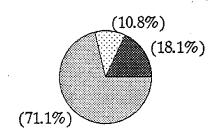
 □ Academic (PhD) ■Private Enterprise

Sex of Conferees



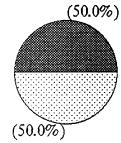
■ Male

Professional Status



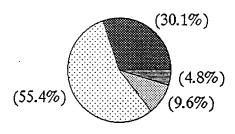
■Student □Post-doc ■Professional

Country Represented



■U.S. ⊠Non-U.S.

GRC's Previously Attended



None □1-5 □5-10 □10+

POINT & LINE DEFECTS IN SEMICONDUCTORS - PLYMOUTH STATE COLLEGE (S) 1994 CONFEREE COMMENTS

SCIENCE:

- 1. It seems it would be useful to present at this meeting more quantity of conceptual talks devoted to general problems of defects. Too many very concrete talks have been presented.
- 2. Should include more innovative research (new fields of defects, etc.).
- 3. The conference seem to attract more theorists than experimentalists. Can this be corrected? It is becoming unbalanced. Poster sessions are too late!

DISCUSSION:

- 4. Excellent, especially discussion.
- 5. A wide variety of important topics were addressed and the ample open discussion provided an even greater exchange of information. Discussion was equally open to all individuals. All attendees were quite accessible. This is very good.
- 6. A well organized meeting with valuable opportunities for wide discussions.

MANAGEMENT:

- 7. Excellent organization by the chairman. Good preparation and mediation of the discussion leaders.
- 8. Excellent conference! The chair did a great job.
- 9. Have morning and afternoon sessions instead of morning and evening sessions.
- Could have longer afternoons.
- 11. Very well organized, good program. Very informative.
- 12. Exceptional, even among GRCs. Conference session leaders were very effective: splendid and exciting discussions/question sessions. Excellent selection of timely and controversial topics still exciting after many years. Many new problems and important ideas.
- 13. 3 1/2 days might be better.
- 14. Very nice format.
- 15. I feel that having the poster sessions after 10:00 p.m. is bad. A late afternoon session would be much better. I feel that there were too many theorists represented, but not enough experimentalists.

ATMOSPHERE:

- 16. Very well organized. Extremely helpful and useful for the scientists from the former Soviet Union for establishing cooperation and receiving the new information.
- 17. Very good.
- 18. Best conference in our field!
- 19. Excellent.

E. ATTENDEE LIST

CONFERENCE #: 94-S-PSS-8

CONFERENCE LOCATION: PLYMOUTH (SOUTH)

CONFERENCE TOPIC: POINT & LINE DEFECTS

.. CONFERENCE DATE: JUL-31-94

CONFERENCE CHAIRMAN: MICHAEL

| | APPLICANT NAME | | DATE SENT | STATUS | PARTIC | APPLIC # |
|----|--|--------|--------------------|--------|----------|----------|
| | ORGANIZATION | | TO CHRMN | | | |
| | CE-SACLAY INSTN | ٠ | JUN-09-94 | ACCPT | SPEAKER | 9418035 |
| DR | DAVID ADLER UNIV OF ILL, URBANA-CHAMPAIGN | · · | JUN-24-94 | ACCPT | ATTENDEE | 9418723 |
| DR | CORNELIS JAMMERLAAN UNIV VAN AMSTERDAM | | JUN-09-94 | RGSTD | ATTENDEE | 9418021 |
| DR | F D AURET UNIVERSITY OF PRETORIA | | MAR-24-94 | RGSTD | ATTENDEE | 9406165 |
| DR | RONALD E BELL UST CENTER FOR MICROELECTRONICS RESEAR | | JUN-09-94 | ACCPT | ATTENDEE | 9417719 |
| | BRIAN R BENNETT NAVAL RESEARCH LAB | | JUN-09-94 | RGSTD | SPEAKER | 9418068 |
| DR | JERZY BERNHOLC NORTH CAROLINA STATE UNIVERSITY | | MAY-26-94 | RGSTD | ATTENDEE | 1014797 |
| DR | PIOTR BOGUSLAWSKI INSTITUTE OF PHYSICS PAN | | MAY-19-94 | RGSTD | SPEAKER | 9415011 |
| DR | VASILY V BULATOV MASS INST OF TECH | | JUL-07-94 | ACCPT | ATTENDEE | 9419322 |
| | MATTHEW J BURHARD LEHIGH UNIVERSITY | | JUN-09-94 | RGSTD | ATTENDEE | 9417907 |
| DR | MARILIA J CALDAS UNIVERSISADE DE SAO PAULO | | JUL-01-94 | ACCPT | ATTENDEE | 9419124 |
| DR | WILLIAM E CARLOS NAVAL RESEARCH LABORATORY | | JUN-09-94 | ACCPT | ATTENDEE | 9417644 |
| DR | EDUARD A CARTIER IBM RESEARCH DIVISION | | JUN-02-94 | ACCPT | SPEAKER | 9416750 |
| | JAMES D CHADI NEC RESEARCH INSTITUTE | | MAR-31-94 | ACCPT | SPEAKER | 9406983 |
| DR | LYNN L CHALFOUN | | JUN-16-94 | ACCPT | ATTENDEE | 9418519 |
| | LEONID CHERNYAK WEIZMANN INSTITUTE OF SCIENCE | | APR-07-94 | RGSTD | ATTENDEE | 9408195 |
| | PAUL H CITRIN AT&T BELL LABORATORIES | | APR-14-94 | ACCPT | SPEAKER | 9409365 |
| DR | BERNARD CLERJAUD UNIVERSITE PIERRE ET MARIE CURIE | | MAY-26-94 | RGSTD | DISC LDR | 9416069 |
| DR | NICHOLAS E COWERN PHILIPS RESEARCH | | JUN-16-94 | ACCPT | ATTENDEE | 9418399 |
| DR | BRAIN R DAVIDSON IMPERIAL COLLEGE, ICR SEMICONDUCTOR | , none | APR-2 <u>1</u> -94 | RGSTD | ATTENDEE | 9410710 |
| DR | GORDON DAVIES PHYSICS DEPARTMENT | | APR-07-94 | RGSTD | ATTENDEE | 9407725 |
| | PETER J DREVINSKY U.S. AIR FORCE | | JUN-09-94 | CANCEL | ATTENDEE | 9417909 |
| | | | | | | |

CONFERENCE LOCATION: PLYMOUTH (SOUTH)

CONFERENCE TOPIC: POINT & LINE DEFECTS IN SE

CONFERENCE DATE: JUL-31-94

CONFERENCE CHAIRMAN: MICHAEL

| | APPLICANT NAME ORGANIZATION | DATE SENT TO CHRMN | STATUS | PARTIC | APPLIC # NEW ST. |
|----|--|------------------------|--------|---------------------|------------------|
| | VADIM V EMTSEV A.F. IOFFE PHYSICO-TECHNICAL INSTITUTE, | MAY-13-94 | RGSTD | ATTENDEE | 9413501 |
| DR | STEFAN K ESTREICHER TEXAS TECH UNIVERSITY | MAR-24-94 | RGSTD | SPEAKER | 9404859 |
| | BORIS Y FARBER ROSEMOUNT ANALYTICAL INC | JUN-09-94 | RGSTD | SPEAKER | 9418040 |
| DR | LEONARD C FELDMAN AT&T BELL LABORATORIES | APR-14-94 | RGSTD | V CHAIR | 9408487 |
| DR | EUGENE A FITZGERALD AT & T BELL LABORATORIES | MAY-19-94 | RGSTD | DISC LDR | 9415601 |
| | W. B FOWLER LEHIGH UNIVERSITY | JUN-16-94 | RGSTD | ATTENDEE | 9418529 |
| DR | VLADIMIR GAVRYUSHIN VILNNIUS UNIV, LAB OF NONLINEAR SPECT | MAY-13-94 | ACCPT | ATTENDEE | 9413617 |
| | HAFLIDI P GISLASON UNIVERSITY OF ICELAND | JUN-16-94 | ACCPT | ATTENDEE | . 1018589 |
| | EVAN R GLASER NAVAL RESEARCH LABORATORY | MAY-13-94 | RGSTD | SPEAKER | 9414403 |
| | ULRICH M GOELSELE MAX-PLANCK-INSTITUTE OF MICROSTRUCTURE | MAY-19-94 | | | 9415604 |
| | UNIVERSITY OF AMSTERDAM | MAR-24-94 | | | 9404861 |
| | UNIVERSITY OF PADERBORN | MAY-26-94 | ACCPT | | |
| | HERMANN G GRIMMEISS UNIVERSITY OF LUND EUGENE E HALLER | | ACCPT | | |
| | UNIVERSITY OF CALIFORNIA BERKELEY | APR-21-94 APR-29-94 | | SPEAKER ATTENDEE | |
| | PURDUE UNIVERSITY AKIRA ISHIBASHI | JUN-16-94 | CANCEL | SPEAKER | ` |
| | SUNY CORPORATION RESEARCH CENTER WOLFGANG JANTSCH | MAY-26-94 | RGSTD | DISC LDR | |
| | JOHANNES KEPLER UNIVERSITAT NOBLE M JOHNSON | APR-29-94 | RĠSTD | SPEAKER | |
| DR | XEROX PARC R JONES | APR-21-94 | RGSTD | SPEAKER | 9409595 |
| | UNIVERSITY OF EXETER BRUNO KARL MEYER | JUN-24-94 | ACCPT | SPEAKER | 9418826 |
| DR | TECH UNIV MUNCHEN HIROSHI KATAYAMA-YOSHIDA | JUN-09-94 | RGSTD | ATTENDEE | 9417997 |
| DR | TOHOBU UNIVERSITY KAREN L KAVANAGH | MAY-13-94 | RGSTD | SPEAKER | 9413502 |
| DR | JCSD THOMAS A KENNEDY NAVAL RESEARCH LAB | JUN-24-94 | ACCPT | ATTENDEE | 9418716 |

CONFERENCE #: 94-S-PSS-8

CONFERENCE LOCATION: PLYMOUTH (SOUTH)

CONFERENCE TOPIC: POINT & LINE DEFECTS IN S

NEW S

ACCPT

CONFERENCE DATE: JUL-31-94

CONFERENCE CHAIRMAN: MICHAEL

| | APPLICANT NAME ORGANIZATION | DATE SENT TO CHRMN | STATUS | PARTIC | APPLIC # |
|------|--|-----------------------|--------|----------|----------|
| DR | LIONEL C KIMERLING | JUN-16-94 | ACCPT | ATTENDEE | 9418526 |
| DR | PAUL MARIA KOENRAAD EINDHOVEN UNIVERSITY OF TECHNOLOGY | JUL-07-94 | ACCPT | ATTENDEE | 9419462 |
| DR | FREDRICH K KOSCHNICK UNIVERSITY OF PADERBORN | MAY-26-94 | ACCPT | ATTENDEE | 9416288 |
| DR | SERGEI V KOVESHNIKOV UNIVERSITY OF NORTH CAROLINA | JUL-01-94 | ACCPT | ATTENDEE | 9419109 |
| DR | HIROSHI KUKIMOTO TOKYO INST OF TECH | JUN-24-94 | ACCPT | DISC LDR | 9418825 |
| | MICHAEL KUNZER FRAUNHOFER INSTITUTE FOR APPLIED | APR-14-94 | RGSTD | ATTENDEE | 9409362 |
| DR | PAOHUA KUO STANFORD UNIV | JUL-07-94 | ACCPT | ATTENDEE | 9419320 |
| DR | PAOHUA KUO STANFORD UNIVERSITY | JUL-14-94 | OPEN | ATTENDEE | 9419510 |
| DR | ERIC P KVAM PURDUE UNIVERSITY | JUN-02-94 | ACCPT | ATTENDEE | 1014725 |
| DR | J M LANGER INST PHYS POLISH AC SCI | MAY-19-94 | RGSTD | DISC LDR | 1014764 |
| - DR | JAMES P LAVINE EASTMAN KODAK COMPANY | MAR-24-94 | CANCEL | ATTENDEE | 9404763 |
| DR | FRANCOISE K LEGOUES IBM T.J. WATSON RESEARCH CENTER | APR-14-94 | RGSTD | SPEAKER | 9408828 |
| DR | HARTMUT S LEIPNER TOHOKU UNIVERSITY | APR-29-94 | RGSTD | ATTENDEE | 9411717 |
| DR | ZHONGNING LIANG GRONINGEN UNIVERSITY | JUN-09-94 | ACCPT | ATTENDEE | 9417483 |
| DR | ROGER L LICHTI TEXAS TECH UNIVERSITY | APR-21-94 | RGSTD | ATTENDEE | 9410182 |
| DR | JEROME C LICINI LEHIGH UNIVERSITY | JUN-24-94 | ACCPT | ATTENDEE | 1014767 |
| DR | J. LENNART LINDSTROM LINLISPING UNIVERSITY | MAR-24-94 | RGSTD | ATTENDEE | 9406205 |
| | ROBERT MAGERLE UNIVERSITAT KONSTANZ | JUN-02-94 | ACCPT | ATTENDEE | 9417002 |
| DR | KARIN MAIER FRAUNHOFER-IAF | APR-14-94 | CANCEL | ATTENDEE | 9409364 |
| DR | PHILLIP W MASON LEHIGH UNIVERSITY | MAY-26-94 | RGSTD | ATTENDEE | 9416331 |
| | SEAMUS A MCQUAID INTERDISCIPLINARY RESEARCH CENTRE FOR | APR-21-94 | RGSTD | ATTENDEE | 9410271 |
| | MICHAEL S METHFESSEL INST F HALBLEITERPHYSIK | JUN-09-94 | ACCPT | ATTENDEE | 9418027 |
| | JURGEN MICHEL MASSACHUSETTS INSTITUTE OF TECHOLOGY | JUN-16-94 | ACCPT | ATTENDEE | 1014738 |

NAVEL RESEARCH LAB

CONFERENCE LOCATION: PLYMOUTH (SOUTH)

CONFERENCE TOPIC: POINT & LINE DEFECTS IN S

NEW ST

CONFERENCE DATE: JUL-31-94

STAVOLA

CONFERENCE CHAIRMAN: MICHAEL

APPLICANT NAME DATE SENT STATUS PARTIC APPLIC # ORGANIZATION TO CHRMN DR MASASHI MIZUTA APR-21-94 ATTENDEE RGSTD 1014771 NEC CORPORATION A MONEMAR DR BO MAR-24-94 RGSTD DISC LDR 9404860 LINKOPING UNIVERSITY DR FREDERICK F MOREHEAD JUN-09-94 RGSTD ATTENDEE 9417872 SEMICONDUCTOR RES. AND DE. CTR., IBM DR CAROLINE G MORGAN MAR-31-94 RGSTD ATTENDEE 9407176 WAYNE STATE UNIVERSITY DR MICHAEL T MORSE JUN-16-94 ACCPT ATTENDEE 9418521 MIT DR EDWARD M NADGORNY APR-21-94 **RGSTD** ATTENDEE 9410492 MICHIGAN TECHNOLOGICAL UNIVERSITY DR KAZUSHI NAKANO JUL-14-94 ACCPT SPEAKER 9419633 SONY CORPORATION RESEARCH CENTER DR HELENA V NAZARE APR-29-94 RGSTD ATTENDEE 9410973 UNIVERSITY OF AVEIRO DR RONALD C NEWMAN APR-21-94 **RGSTD** 9410272 SPEAKER INTERDISCIPLINARY RESEARCH CENTRE FOR DR BRAIN C NIELSEN MAY-05-94 RGSTD ATTENDEE 9412386 UNIVERSITY OF AARHUS DR LAMBERTUS NIESEN JUN-09-94 ACCPT ATTENDEE 9418044 NUCLEAR SOLID STATE PHYSICS MATERIALS-DR JOHN E NORTHRUP JUN-09-94 **RGSTD** SPEAKER 9417873 XEROX PARC DR ARNE NYLANDSTED LARSEN MAY-26-94 **RGSTD** SPEAKER 9415836 AARHUS UNIVERSITY DR ATUSUSHI OSHIYAMA MAY-13-94 ACCPT ATTENDEE 9413504 FUNDAMENTAL RESEARCH LABORATORIS DR SERGI OSTAPENKO JUN-02-94 ACCPT ATTENDEE 9417180 UNIVERSITY OF FLORIDA DR H JORG OSTEN MAY-19-94 **RGSTD** SPEAKER 9415335 INST OF SEMICONDUCTOR PHYSICS DR JORG PALM JUN-16-94 ACCPT ATTENDEE 9418523 MIT DR DEREK W PALMER APR-14-94 RGSTD ATTENDEE 9409360 UNIVERSITY OF SUSSEX DR YONGJO PARK JUN-24-94 ACCPT ATTENDEE 9418999 CARMEIGE MELON UNIVERSITY DR EDWARD H POINDEXTER APR-21-94 RGSTD DISC LDR 9410273 ARMY RESEARCH LABORATORY DR ARTI PRASAD JUN-24-94 ACCPT ATTENDEE 9418761 UNIVERSITY OF CALIFORNIA T PRATER DR JOHN APR-14-94 RGSTD ATTENDEE 9409180 ARMY RESEARCH OFFICE DR SHARKA M PROKES MAY-26-94 ACCPT ATTENDEE 9416285

CONFERENCE #: 94-5-PSS-8

CONFERENCE LOCATION: PLYMOUTH (SOUTH)

CONFERENCE TOPIC: POINT & LINE DEFECTS IN SE

NEW ST

CONFERENCE DATE: JUL-31-94

CONFERENCE CHAIRMAN: MICHAEL

| APPLICANT NAME ORGANIZATION | DATE SENT TO CHRMN | STATUS | PARTIC | APPLIC # | |
|--|-----------------------|---|-------------|---|---|
| DR GEDIMINAS RACIUKAITIS | JUN-16-94 | WTLIST | ATTENDEE | 94184 01 | |
| VILNIUS UNIVERSITY | | | | | |
| DR FRANK B RASMUSSEN | MAY-05-94 | RGSTD | ATTENDEE | 9412388 | |
| UNIVERSITY OF AARHUS | | | | | |
| **MISSING RCD. CHRMN DATE | | | | | |
| DR ALEXANDER I RYSKIN | JUL-14-94 | ACCPT | ATTENDEE | 9419490 | |
| S. I. VAVIALOV STATE OPTICAL INSTITUTE | | | | | |
| DR AKIRA SAKAI | JUN-24-94 | ACCPT | ATTENDEE | 9418824 | |
| MICROELECTRONICS RESEARCH LAB | | | | | |
| DR MATTHIAS SCHEFFLER | MAY-13-94 | RGSTD | DISC LDR | 9414405 | |
| FRITZ-HABER-INSTITUT | | | | | |
| Joseph Schick | MAR-31-94 | RGSTD | ATTENDEE | 1000725 | |
| Dept. of Physics | | | | | |
| DR STEFAN SCHUPPLER | JUN-16-94 | ACCPT | ATTENDEE | 9418530 | |
| AT&T BELL LABORATORIES | | 5 | | | |
| DR CARLETON H SEAGER | JUN-09-94 | ACCPT | ATTENDEE | 9418029 | |
| SANDIA NATIONAL LABORATORIES | | | | _ | |
| **MISSING RCD. CHRMN DATE | | | | | |
| DR MOISZEI K SHEINKMAN | JUL-14-94 | ACCPT | ATTENDEE | 9419491 | |
| INSTITUTE OF SEMICONDUCTOR PHYSICS | | | | | |
| DR LAWRENCE C SNYDER | MAY-19-94 | RGSTD | ATTENDEE | 9414901 | |
| STATE UNIV OF NEW YORK, ALBANY | | | | | |
| DR FENG SONGLIN | MAY-13-94 | RGSTD | ATTENDEE | 9414017 | |
| CHINESE ACADEMY OF SCIENCES | , | , 110012 | | ,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,, | |
| DR JOHANN M SPAETH | MAY-26-94 | ACCPT | SPEAKER | 9416286 | |
| UNIVERSITY OF PADERBORN | | ,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,, | | 7.13233 | |
| DR PETER STALLINGA | MAY-26-94 | ACCPT | ATTENDEE | 9416332 | |
| UNIVERSITEIT VAN AMSTERDAM | 1011 40 74 | | ,,,,,,,,,, | 7113332 | |
| DR MICHAEL J STAVOLA | MAY-26-94 | RGSTD | CHAIR | 9415832 | |
| LEHIGH UNIVERSITY | 120. 40 74 | | | | |
| DR MARTIN STUTZMANN | MAR-31-94 | RGSTD | ATTENDEE | 9406573 | • |
| TECHNICAL UNIVERSITY MUNICH | MAK 31 74 | | X E.1.5 E.E |) - 003.5 | |
| DR KOJI SUMINO | JUN-02-94 | RGSTD | ATTENDEE | 9417183 | |
| INSTITUTE FOR MATERIALS RESEARCH | 30R 02 74 | KGSTD | ATTEMPEL | 7411103 | |
| DR JERRY D TERSOFF | MAY-05-94 | RGSTD | SPEAKER | 9412714 | |
| · | MA1 - 03 - 74 | K4515 | OF EARLY | 7416714 | |
| IBM DR ANNALENA K THILDERKVIST | JUN-02-94 | RGSTD | ATTENDEE | 9417003 | |
| UNIVERSITY OF LUND | JUN-02 34 | RUSTO | ATTEMBLE | 7411003 | |
| | APR-21-94 | ACCPT | ATTENDEE | 1014742 | |
| DR KLAUS THONKE | AFR-61-74 | Acres 1 | At this bis | | |
| UNIVERSITAT ULM | JUN-09-94 | ACCPT | ATTENDEE | 9418048 | |
| DR LARS P TILLY | | ACCE | ALIENVEE | 77 100 7 0 | |
| _ IBM | WAY 24 0/ | DCCTD | ATTENDEE | 9/.16044 | |
| DR STEPHEN J UFTRING | MAY-26-94 | RGSTD | ATTENUEE | 74 10UQQ | |
| LEHIGH UNIVERSITY | um 00 01 | 20072 | 0100 100 | 0/14751 | |
| DR CHRIS G VAN DE WALLE | JUN-02-94 | RGSTD | DISC LDR | 9416751 | |
| XEROX PARC | | | | • | |

CONFERENCE #: 94-S-PSS-8

LEHIGH UNIVERSITY

CONFERENCE LOCATION: PLYMOUTH (SOUTH)

CONFERENCE TOPIC: POINT & LINE DEFECTS IN SE

CONFERENCE DATE: JUL-31-94

CONFERENCE CHAIRMAN: MICHAEL STAVOLA

| | APPLICANT NAME ORGANIZATION | DATE SENT TO CHRMN | STATUS | PARTIC | APPLIC # | NEW ST |
|----|--|-----------------------|--------|----------|----------|-------------|
| DR | KAZUMI WADA - | JUN-02-94 | ACCPT | ATTENDEE | 9416752 | |
| | NIT LSI LABS SCOTT N WALCK | MAY-19-94 | RGSTD | ATTENDEE | 9415237 | |
| | LEHIGH UNIVERSITY WILLIAM W WARREN | MAR-24-94 | RGSTD | ATTENDEE | 9405473 | |
| | OREGON STATE UNIVERSITY GEORGE D WATKINS | MAY-26-94 | RGSTD | ATTENDEE | 9416329 | <i>μ. σ</i> |
| | LEHIGH UNIVERSITY | | | | | |
| | EICKE R WEBER UC BERKELEY | MAY-05-94 | ACCPT | | 9412713 | |
| DR | JOERG WEBER MAX-PLANCK-INSTITUT F FESTKORPESFORSCH | JUN-16-94 | ACCPT | DISC LDR | 1014777 | |
| DR | BRUCE WESSELS NORTHWESTERN UNIVERSITY | MAR-31-94 | ACCPT | ATTENDEE | 1014801 | |
| | PHILLIP M WILLIAMS | MAY-26-94 | ACCPT | ATTENDEE | 9416330 | |
| | LEHIGH UNIVERSITY ARTHUR F WILLOUGHBY | MAR-24-94 | RGSTD | ATTENDEE | 9404237 | |
| DR | SOUTHAMPTON UNIVESITY NEAL D WILSEY | JUN-24-94 | ACCPT | ATTENDEE | 9418760 | |
| | NAVEL RESEARCH LABORATORY FREDERICK P WITTEL | MAY-26-94 | ACCPT | ATTENDEE | 9415834 | |
| | BOSTON UNIVERSITY YAHONG XIE | APR-21-94 | RGSTD | ATTENDEE | 1018327 | |
| | AT&T BELL LABORATORIES | | ACCPT | | | |
| DR | YANG YANG LEHIGH UNIVERSITY PHYSICS DEPT | | | ٠ | | |
| DR | JIEFEI ZHENG | JUN-09- 94 | ACCPT | ATTENDEE | 9418079 | |

| ATTENDEES AVAILABLE: | -12 |
|----------------------|-------|
| GUESTS AVAILABLE | -9 |
| TOTAL OPEN | 1 |
| ATTENDEES ACCEPTE | D 121 |
| REGISTERED | 64 |
| CANCELLED | 4 |
| WAIT LISTED | 1 |
| GUESTS ACCEPTED | 9 |
| | |

| PROVED | BY: | • • | DATE: |
|--------|-----|---------|-------|
| | | | |